

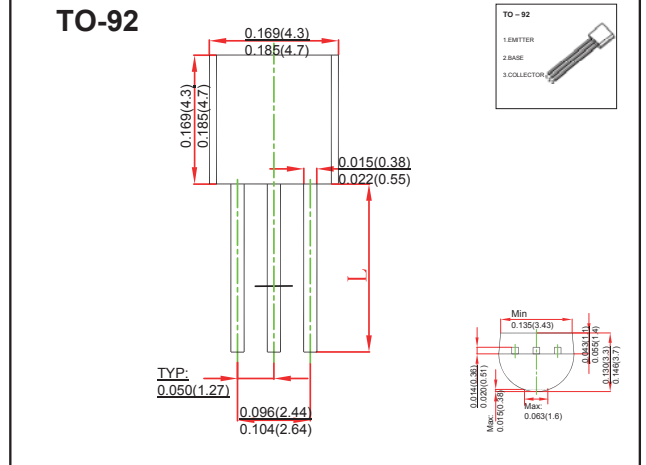
## TO-92 Plastic-Encapsulate Transistors

### FEATURES

- General Purpose Amplifier Transistor
- TRANSISTOR (NPN)

### MECHANICAL DATA

- Case style: TO-92 molded plastic
- Mounting position: any



## MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CB0</sub>	Collector-Base Voltage	60	V
V <sub>CE0</sub>	Collector-Emitter Voltage	40	V
V <sub>EB0</sub>	Emitter-Base Voltage	3	V
I <sub>C</sub>	Collector Current -Continuous	0.6	A
P <sub>D</sub>	Collector Power Dissipation	625	mW
R <sub>θJA</sub>	Thermal Resistance from Junction to Ambient	200	°C/W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55--+150	°C

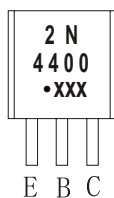
### ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
2N4400	TO-92	Bulk	1000pcs/Bag
2N4400-TA	TO-92	Tape	2000pcs/Box

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =0.1mA, I <sub>E</sub> =0	60			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =1mA, I <sub>B</sub> =0	40			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =0.1mA, I <sub>C</sub> =0	6			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =60V, I <sub>E</sub> =0			0.1	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =6V, I <sub>C</sub> =0			0.1	μA
DC current gain	h <sub>FE</sub> *	V <sub>CE</sub> =1V, I <sub>C</sub> =1mA	20			
		V <sub>CE</sub> =1V, I <sub>C</sub> =10mA	40			
		V <sub>CE</sub> =1V, I <sub>C</sub> =150mA	50		150	
		V <sub>CE</sub> =2V, I <sub>C</sub> =500mA	20			
Collector-emitter saturation voltage	V <sub>CE(sat)</sub> *	I <sub>C</sub> =150mA, I <sub>B</sub> =15mA			0.4	V
		I <sub>C</sub> =500mA, I <sub>B</sub> =50mA			0.75	
Base-emitter saturation voltage	V <sub>BE(sat)</sub> *	I <sub>C</sub> =150mA, I <sub>B</sub> =15mA	0.75		0.95	
		I <sub>C</sub> =500mA, I <sub>B</sub> =50mA			1.2	V
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> =5V, I <sub>E</sub> =0, f=1MHz			6.5	pF
Emitter input capacitance	C <sub>ib</sub>	V <sub>EB</sub> =5V, I <sub>C</sub> =0, f=1MHz			30	p
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =20mA, f=100MHz	200			MHz

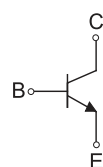
\*Pulse test: pulse width ≤300μs, duty cycles ≤2.0%.

### MARKING

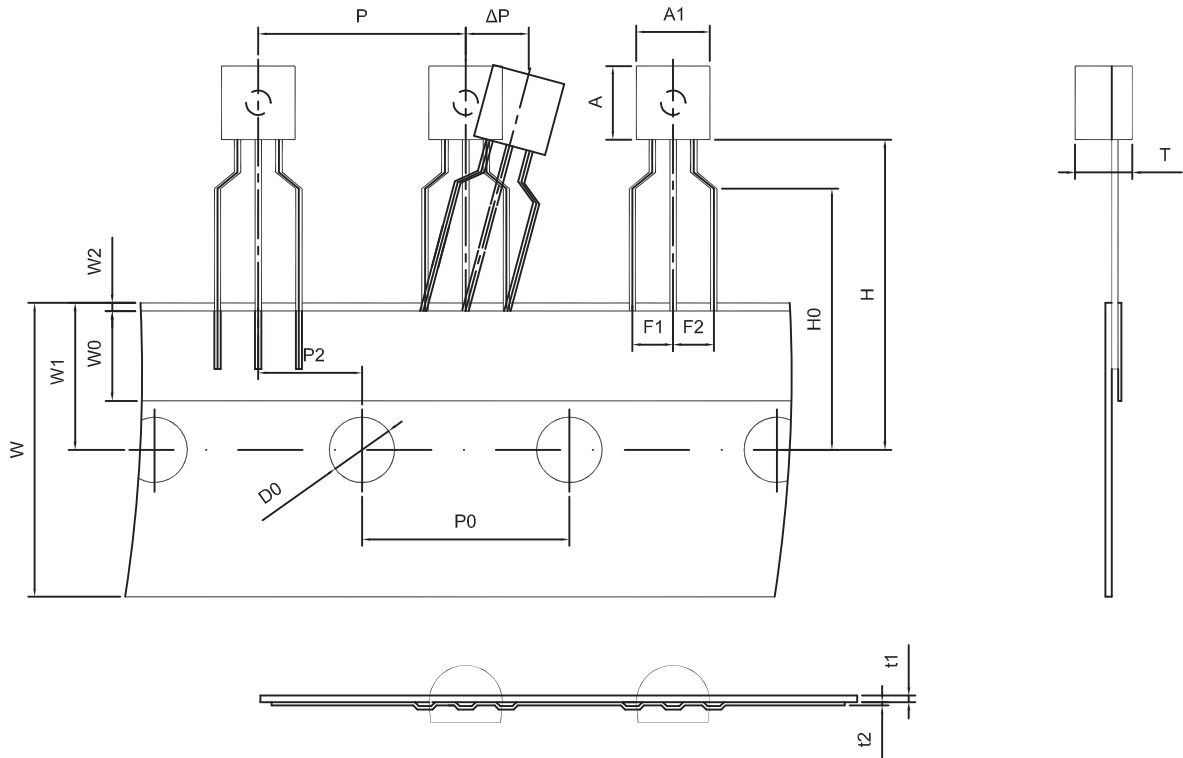


2N4400=Device code  
 Solid dot=Green molding compound device,  
 if none, the normal device  
 XXX=Code

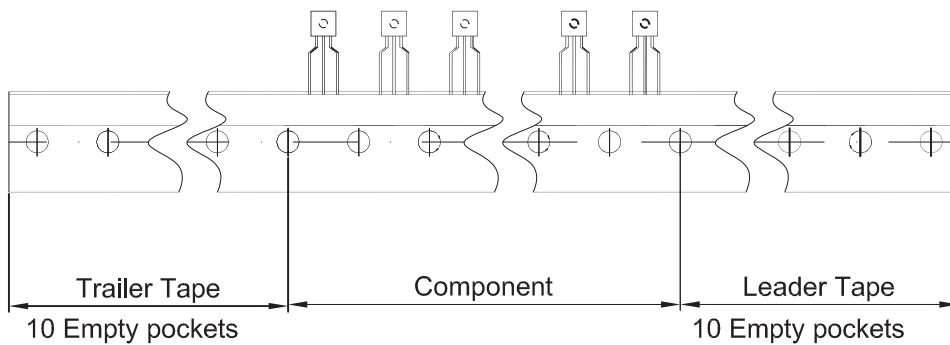
### Equivalent Circuit



TO-92 PACKAGE TAPEING DIMENSION



Dimiensions are in millimeter								
A1	A	T	P	P0	P2	F1	F2	W
4.5	4.5	3.5	12.7	12.7	6.35	2.5	2.5	18.0
W0	W1	W2	H	H0	D0	t1	t2	ΔP
6.0	9.0	1.0 MAX.	19.0	16.0	4.0	0.4	0.2	0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92	2000 pcs	333×162×43	20,000 pcs	350×340×250